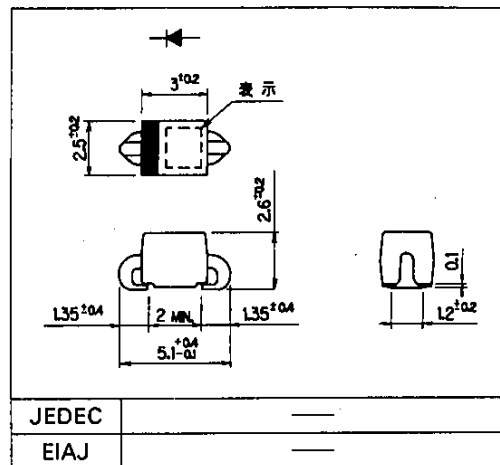


ショットキーバリアダイオード

SCHOTTKY BARRIER DIODE

■外形寸法：Outline Drawings



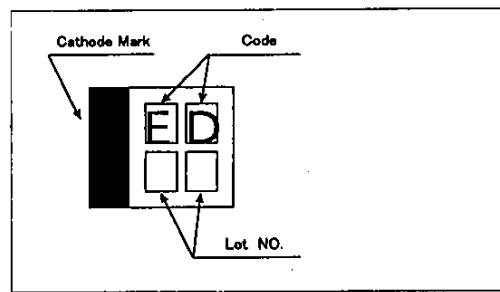
■特長：Features

- 表面実装が可能
Surface mount device
- 低 V_F
Low V_F
- スイッチングスピードが非常に速い
Super high speed switching.
- プレーナー技術による高信頼性
High reliability by planer design.

■用途：Applications

- 高速電力スイッチング
High speed power switching.

■表示：Marking



■定格と特性：Maximum Ratings and Characteristics

●絶対最大定格：Absolute Maximum Ratings

Items	Symbols	Conditions	Ratings	Units
ピーク繰り返し逆電圧 Repetitive Peak Reverse Voltage	V_{RRM}		90	V
ピーク非繰り返し逆電圧 Non-Repetitive Peak Reverse Voltage	V_{RSM}	$t_w = 500\text{ns}$ duty = $\frac{1}{10}$	100	V
平均出力電流 Average Output Current	I_o	抵抗負荷 Resistive Load $T_l = 110^\circ\text{C}$	1.0*	A
サージ電流 Surge Current	I_{FSM}	正弦波 Sine Wave 10ms	30	A
接合温度 Operating Junction Temperature	T_j		-40 ~ +125	$^\circ\text{C}$
保存温度 Storage Temperature	T_{stg}		-40 ~ +125	$^\circ\text{C}$

* ガラスエポキシ基板に装着、ランド寸法15×15mm

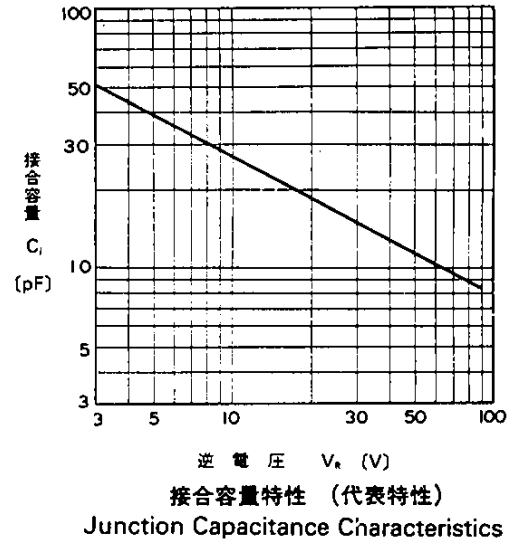
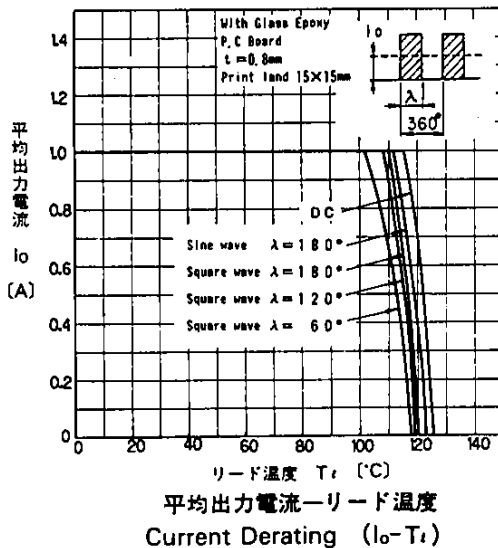
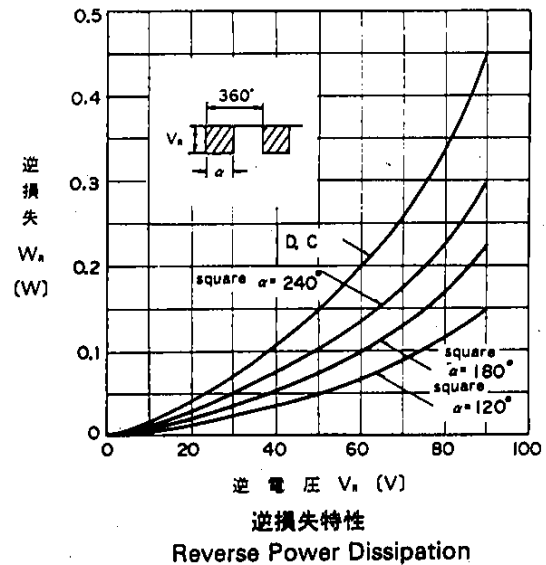
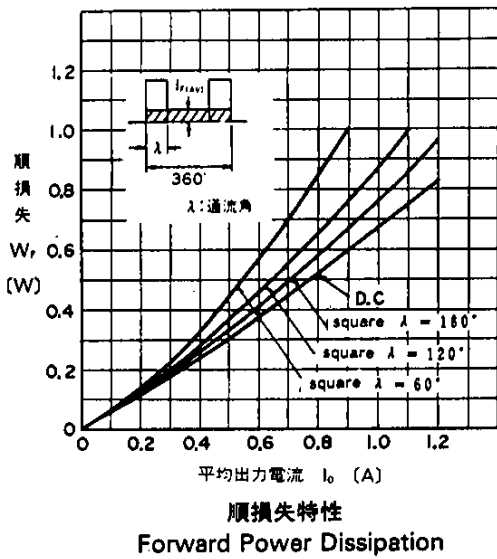
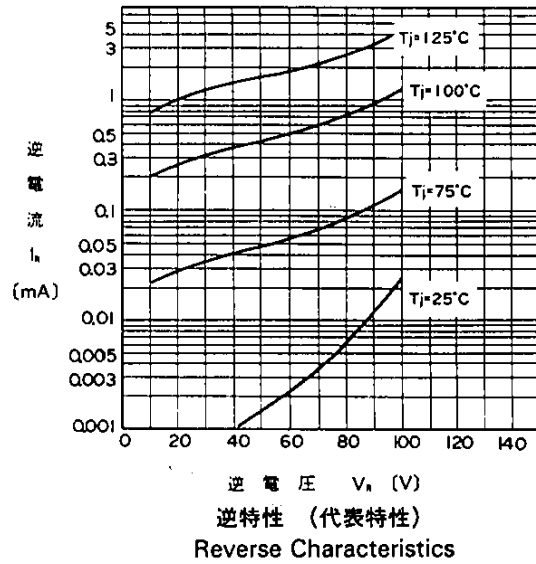
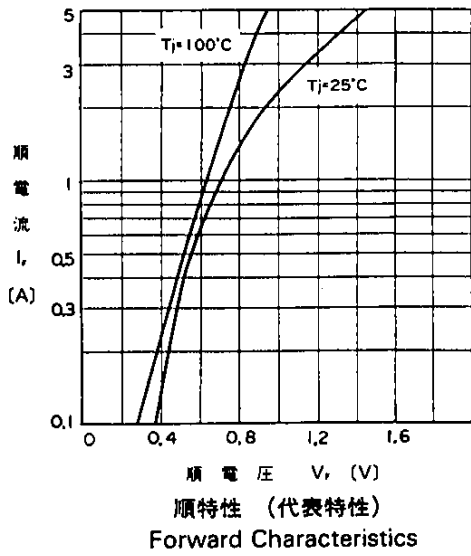
* Mounted to glass fabric base epoxy resin printed circuits

●電気的特性(特に指定がない限り周囲温度 $T_a = 25^\circ\text{C}$ とする)

Electrical Characteristics ($T_a = 25^\circ\text{C}$ Unless otherwise specified)

Items	Symbols	Conditions	Max.	Units
順電圧 Forward Voltage Drop	V_{FM}	$I_{FM} = 1.0\text{A}$	0.85	V
逆電流 Reverse Current	I_{RRM}	$V_R = V_{RRM}$	1.0	mA
熱抵抗 Thermal Resistance	$R_{th(j-l)}$	接合・リード間 junction to lead	120*	$^\circ\text{C/W}$

■特性曲線：Characteristics



A

